NSN 5961-01-321-1918

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-321-1918 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.130 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.0 regulator voltage **Voltage Tolerance In Percent:** -1.0/+1.0 **Current Rating Per Characteristic:** 50.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0